TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WG17FU,TC7WG17FK

#### Triple Schmitt Buffer

#### **Features**

• High-level output current:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ 

at V<sub>CC</sub> = 3 V

• High-speed operation: t<sub>pd</sub> = 4.0 ns (typ.)

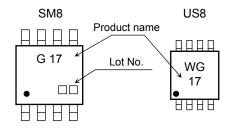
at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

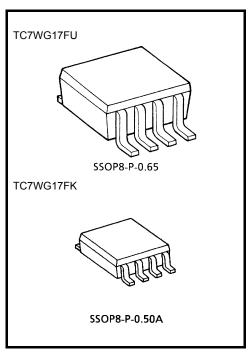
• Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V

• 5.5-V tolerant inputs

• 3.6-V power down protection outputs

#### Marking





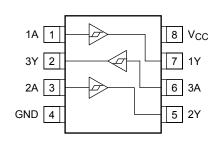
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V
DC output voltage	V <sub>OUT</sub>	-0.5~ 4.6 (Note 1)	V
		-0.5~V <sub>CC</sub> + 0.5 (Note 2)	V
Input diode current	I <sub>IK</sub>	-20	mA
Output diode current	lok	-20 (Note 3)	mA
DC output current	lout	±25	mA
DC V <sub>CC</sub> / ground current	Icc	±50	mA
Power dissipation	PD	300 (SM8) 200 (US8)	mW
Storage temperature	T <sub>stg</sub>	<b>−65~150</b>	°C

### Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0V$ 

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

## **IEC Logic Symbol**



#### **Truth Table**

Α	Υ
L	L
Н	Н

## **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	V	0~3.6 (Note 4)	V	
	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 5)	]	
Output Current	I <sub>OH</sub> /I <sub>OL</sub>	±8.0 (Note 6)		
		±4.0 (Note 7)		
		±3.0 (Note 8)	m A	
		±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)		
Operating temperature	T <sub>opr</sub>	-40~85	°C	

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6: V<sub>CC</sub> = 3.0~3.6 V

Note 7: V<sub>CC</sub> = 2.3~2.7 V

Note 8:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \sim 1.6 \text{ V}$ 

Note 10: V<sub>CC</sub> = 1.1~1.3 V

Note 11:  $V_{CC} = 0.9 \text{ V}$ 

## **Electrical Characteristics**

#### **DC Electrical Characteristics**

Characteristics		Symbol	Tost	Test Condition		٦	Га = 25°C	)	Ta = -40~85°C		Unit
		Symbol	rest Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Ullit
High level				0.9	_	_	0.73	_	0.80		
					1.1	_	_	0.86	_	0.93	-
	l link laval	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \				_	_	1.07	_	1.12	V
	High level	V <sub>P</sub>	_		1.65	_	_	1.23	_	1.25	
					2.3	_	_	1.66	_	1.68	
					3.0	_	_	2.14	_	2.15	
Threshold voltage					0.9	0.18	_	_	0.07	_	V
					1.1	0.26	_	_	0.18	_	
	l and land				1.4	0.36	_	_	0.31		
	Low level	V <sub>N</sub>		_	1.65	0.45	_	_	0.41	_	
					2.3	0.69	_	_	0.64		· 
					3.0	0.96	_	_	0.91	_	
	•				0.9	0.20		0.38	0.15	0.53	
					1.1	0.25		0.41	0.21	0.53	
L hyatarasia yaltaga		V.				0.35		0.48	0.34	0.57	\/
Hysteresis voltage		V <sub>H</sub>	_		1.65	0.42		0.56	0.40	0.60	V
					2.3	0.60		0.74	0.61	0.76	
					3.0	0.79		0.93	0.80	0.94	
	High level	Vон	V <sub>IN</sub> = V <sub>IH</sub>	I <sub>OH</sub> =-0.02 mA	0.9	0.75	_	_	0.75	_	
				$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
				I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
				I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45	_	
				I <sub>OH</sub> = -4.0 mA	2.3~2.7	2.0	_	_	2.0	_	
Output voltage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48	_	V
Output voltage				$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	v
				I <sub>OL</sub> = 0.3 mA	1.1~1.3	_		V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
l	Low level	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IL</sub>	I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
		92		I <sub>OL</sub> = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45	
				I <sub>OL</sub> = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4	
				I <sub>OL</sub> = 8.0 mA	3.0~3.6	_	_	0.4	_	0.4	
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0~5.5V		0~3.6	_	_	±0.1	_	±1.0	μΑ
Power off leakage current		l <sub>OFF</sub>	V <sub>IN</sub> = 0~5 V <sub>OUT</sub> = 0	V <sub>IN</sub> = 0~5.5V V <sub>OUT</sub> = 0~3.6V		_	_	1.0	_	10.0	μΑ
Quiescent supply current		Icc	$V_{IN} = V_{CC}$	or GND	3.6	_		1.0	_	10.0	μА

## AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Ondidotenstios			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Onit
	<sup>t</sup> pLH <sup>t</sup> pHL	$C_L$ = 10 pF, $R_L$ = 1 M $\Omega$	0.9	_	41.3	_	_	_	ns
			1.1~1.3		18.0	25.4	1.0	40.8	
			1.4~1.6		9.5	12.2	1.0	13.5	
			1.65~ 1.95		7.0	8.7	1.0	9.3	
			2.3~2.7		4.7	5.7	1.0	6.2	
			3.0~3.6		3.7	4.5	1.0	4.7	
		$C_L$ = 15 pF, $R_L$ = 1 M $\Omega$	0.9		44.4			_	
			1.1~1.3		19.3	27.7	1.0	46.9	
Propagation delay time			1.4~1.6		10.2	13.1	1.0	14.7	
			1.65~ 1.95		7.5	9.3	1.0	9.9	
			2.3~2.7		5.0	5.9	1.0	6.4	
			3.0~3.6		4.0	4.8	1.0	5.2	
		$C_L$ = 30 pF, $R_L$ = 1 $M\Omega$	0.9		55.8			_	
			1.1~1.3		24.7	36.3	1.0	59.6	
			1.4~1.6		12.9	16.8	1.0	19.2	
			1.65~ 1.95		9.2	11.5	1.0	12.9	
			2.3~2.7		5.9	7.1	1.0	8.3	
			3.0~3.6	_	4.9	5.7	1.0	6.6	
Input capacitance	C <sub>IN</sub>	_	3.6		3		_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 12)	0.9 ~ 3.6	_	11	_		_	pF

Note 12: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

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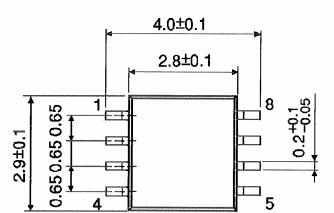
Average operating current can be obtained by the equation:

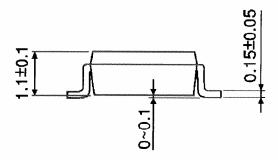
 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ 

Unit: mm

## **Package Dimensions**

SSOP8-P-0.65



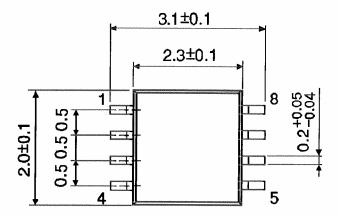


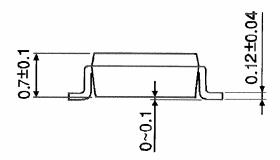
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Weight: 0.02 g (typ.)

## **Package Dimensions**

SSOP8-P-0.50A Unit: mm





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Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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